

# SANYO Semiconductors **DATA SHEET**

# LV4910T — Class-D Audio Power Amplifier BTL 2W × 2ch

#### Overview

LV4910T is a stereo digital amplifier for portable equipment, for example notebook-PC, portable DVD and portable mini-speakers. It is characterized by the use of an original feedback technology to improve sound quality though it is Class-D amplifier, and does not need the LC filter in the output stage.

#### **Features**

- D-class high-efficiency amplifier
- Low pop sound at SW changeover
- Differential input type

#### **Functions**

- 2W stereo digital power amplifier
- Standby switch
- Mute switch
- Various protective circuits (over-current protective, thermal protective, and under-voltage circuits) incorporated

#### **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		6	V
Allowable power dissipation	Pd max	as mounted on the substrate	1.05	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-40 to +150	°C

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#### SANYO Semiconductor Co., Ltd.

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### Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	Vcc		5	V
Operation supply voltage range	V <sub>CC</sub> opg		2.5 to 5.5	V
Recommended load resistance	$R_L$	Speaker	4	Ω

### Electrical Characteristics $Ta=25^{\circ}C,\,V_{CC}=5V,\,f=1kHz,\,R_{L}=4\Omega$

Parameter	Symbol	O and Hitlerine	Ratings			11.5
Parameter		Conditions	min	typ	max	Unit
Standby current	Ist	Current at ST ON			1	μΑ
Current at no signal	I <sub>CCO</sub> 1	At LC filter-less		12	20	mA
Current at Mute	I <sub>CCO</sub> mute	At Mute of speaker		10	16	mA
Voltage gain	VG	V <sub>O</sub> = 0dBm	21	23	25	dB
Channel balance	ΔVG	V <sub>O</sub> = 0dBm	-1	0	1	dB
Output power	PO	THD = 10%		2		W
Total harmonic distortion	THD	P <sub>O</sub> = 0.5W, DIN AUDIO		0.4	0.7	%
Output noise voltage	V <sub>NO</sub>	Rg = 0, DIN AUDIO		100	200	μV
Crosstalk	СТ	V <sub>O</sub> = 0dBm, TUN 1kHz		-60	-40	dB
Ripple rejection ratio	RR	fr = 100Hz, Vr = -10dBm, TUN 100Hz		-40	-30	dB
Common mode rejection ratio	CMRR	V <sub>O</sub> = 0dBm, DIN AUDIO		-60	-40	dB
Mute attenuation value	V <sub>OFF</sub>	V <sub>O</sub> = 0dBm, DIN AUDIO		-80	-70	dB
Oscillation frequency	F <sub>PWM</sub>			300		kHz
Standby ON voltage sensitivity	V <sub>PWROFF</sub>	Standby ON start voltage			1	V
Standby OFF voltage sensitivity	V <sub>PWRON</sub>	Standby OFF start voltage	3			V
Mute ON voltage sensitivity	VMUTEON	Mute ON start voltage			0.5	V
Mute OFF voltage sensitivity	VMUTEOFF	Mute OFF start voltage	2			V

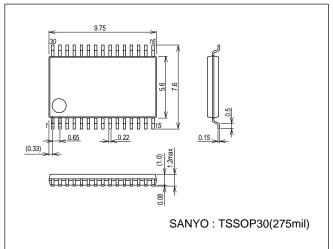
<sup>\*</sup> Electrical characteristics vary depending on the substrate layout and selection of external parts.

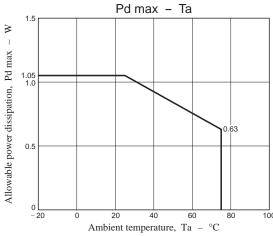
For measurement of the above characteristics, the coil :  $22\mu H$  (Toko Kabushiki Kaisha made D63CB) is used.

# **Package Dimensions**

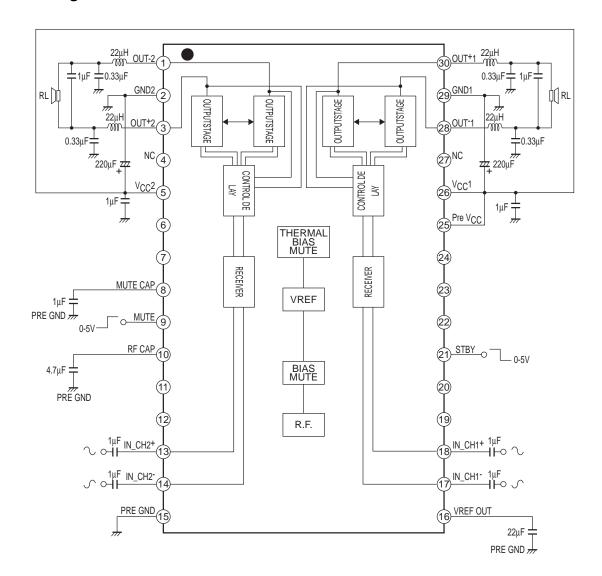
unit: mm (typ)

3259





# **Block Diagram**



# LV4910T

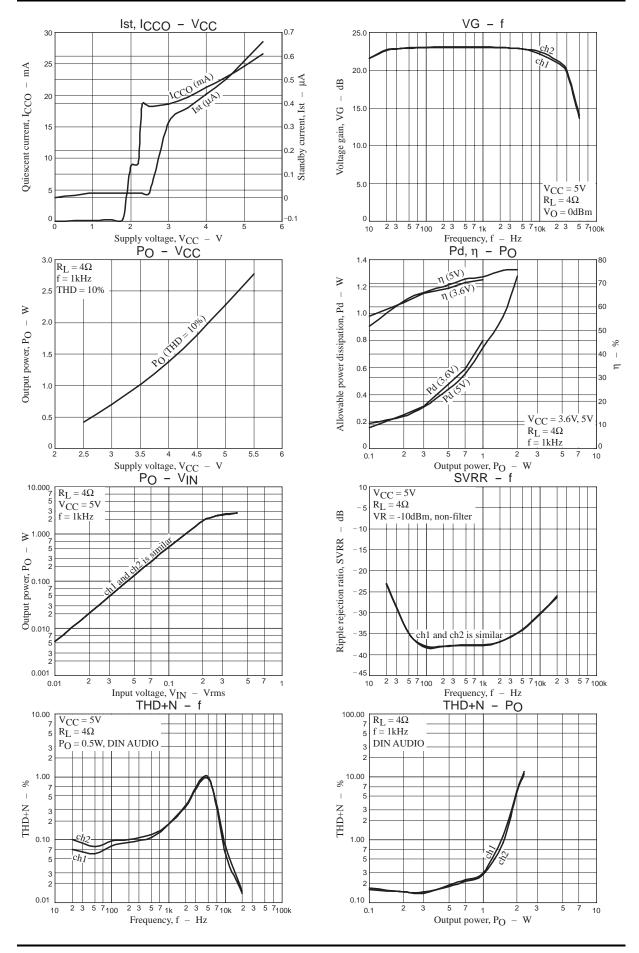
## **Pin Descriptions**

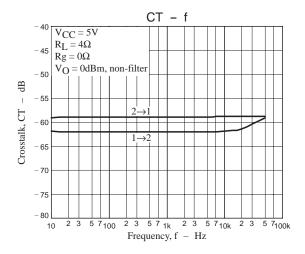
Pin No.	Pin name	Pin voltage (V)	Pin description	Equivalent circuit
1	OUT-2	2.58	Power outputs	A
3	OUT+2			<b>↑</b> T
28	OUT-1			
30	OUT+1			<b>1 1 1 1 1 1 1 1 1 1</b>
				<b>↑</b> <del> </del>
				<b>*</b> •
				T Z
				n n
2	GND2	0		
4	NC	0	Non-connection	
			• Non-connection	
5	V <sub>CC</sub> 2	5		
6	NC		Non-connection	
7	NC		Non-connection	
8	MUTE CAP	4.9	Connection for the mute switch On/Off impulse noise	<b>*</b>
			reduction capacitor	
				<b>→</b>
				<b>†</b>
				\$20kΩ
				\$300kQ
				\$300kΩ 1€
				m m m
9	MUTE		Mute On/Off switch	
			• 2 to 5.5V : Mute Off	<b>1</b>
			• 0 to 0.7V : Mute On	
				4001.0
				100kΩ ξ
				<b>★</b> \$20kΩ
				≹300kΩ
				m m m
10	RF CAP	2.6	Ripple filter reference	
				T T
				\$100kΩ
				300Ω 45kΩ
				\$100kΩ   T
				T \$100x22
				*
				m m m
11	NC		Non-connection	
12	NC		Non-connection	
13	IN_ch2+	2.4	Signal input	<b>A</b>
14	IN_ch2			Ţ
17	IN_ch1 <sup>-</sup>			<u> </u>
18	IN_ch1+			3000
				300Ω
				T 30kΩ≸
				, v , m
		<u> </u>		

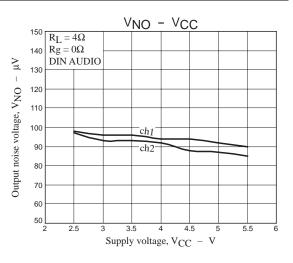
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# LV4910T

Pin No.	Pin name	Pin voltage (V)	Pin description	Equivalent circuit
15	PRE GND	0		
16	VREF OUT	2.55	VREF amplifier reference	
19	NC		Non-connection	
20	NC		Non-connection	
21	STBY		• STBY On/Off switch • 0 to 1V : Power Off • 3 to 5.5V : Power On	\$20kΩ
22	NC		Non-connection	
23	NC		Non-connection	
24	NC		Non-connection	
25	PRE V <sub>CC</sub>	5		
26	V <sub>CC</sub> 1	5		
27	NC		Non-connection	
29	GND1	0		







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